Application No. 10/789,423

Amendment dated December 19, 2005

Reply to Office Action of September 20, 2005

REMARKS

Claims 2 and 5 have been rejected under 35 USC 102(b) as being anticipated by Hayes (U.S.

Docket No.: 20659/0203719-US0

Patent No. 6,077,380). Claim 4 has been rejected under 35 USC 103(1) as being unpatentable over

Hayes in view of Kuramoto (U.S. Patent Publication No. 2001/0020744).

Amended independent claim 5 is directed to a microelectromechanical device of at least two

components, wherein at least one component comprises two substrates with thermoelectric material

arranged on the substrates which are joined together by solder. These features are disclosed in

paragraphs 0064-0066, 0071, and 0072, and in Figures 6 a, 6b, and 7.

Amended dependent claim 6 recites that the thermoelectric material is arranged as a Peltier

cooler or a thermoelectric transducer.

New dependent claim 22 recites that at least one component has one of an electrical, a

thermal, and a bonding functionality. These features are disclosed in original claim 5 and in

paragraph 0015.

Hayes describes solid spheres coated with a low melting material and a method of forming

those spheres. The spheres are used, for example, as a solder for joining arrays. The coated spheres

are formed by merging droplets of two different materials where the lower melting material is

deposited as a coating on a droplet of the higher melting material. Preferred materials are copper as

the high melting material and a solder, e.g. bismuth or gold, as the low melting material. This

process leads to the formation of spheres coated with a solder. The spheres might be used for

joining substrates, in microelectronical devices for example (see Fig. 6).

Amended claim 5, on the other hand, is directed to a microelectromechanical device

comprising at least two components, whereby at least one of the components has two substrates

joined by a solder. A thermoelectric material is arranged on each of the substrates. Furthermore, as

recited in claim 6, the thermoelectric material is in the form of a Peltier element or a thermoelectric

transducer.

6

Application No. 10/789,423

Amendment dated December 19, 2005

Reply to Office Action of September 20, 2005

The device according to amended claim 5 has a complex, layered construction. At least two

Docket No.: 20659/0203719-US0

substrates with thermoelectric material are joined by the action of a eutectic mixture of gold and

bismuth to one component, which is then joined using the same solder to at least one other

component, thereby forming a multilayered device.

For example, the component having the thermoelectric material can be used as a cooling

device which can be bonded to a laser chip or laser diode. Hence, the device according to amended

claims 5 provides a thermoelectric element which can be joined in a very simple manner to another

electrical or thermal device as the second component. Due to the use of a eutectic bismuth-gold

mixture, the device can be assembled at low temperatures (below 271°C). This allows for a gentle

and simplified production of the complex microelectromechanical device.

Furthermore, it is known that the composition of multicomponent devices changes over time

as a result of preferential sputtering of different elements. This effect can be avoided or reduced by

using the eutectic Bi-Au-mixture.

The device as depicted in Figure 6 of Hayes merely shows a microelectronical device joined

to a substrate through solder-coated spheres, and does not provide any further information about the

microelectronical device. Hayes also does not suggest the use of thermoelectric material for

forming a thermoelectric device, and combining the device with another thermal or electrical

device.

Kuramoto relates to a method of forming a solder film on a metallic surface. This is

achieved by depositing tacky substrates such as benzotriazole or imidazol derivatives on the

metallic surface followed by applying the solder. The solder is then molten under formation of thin

solder film. Examples of solders are eutectic bismuth alloys, as disclosed in paragraphs 0063-0065.

The solder particles have sizes of 1 to 500 µm (see paragraph 0062). The formed solder film has a

thickness of between 5 and 200 µm (see claims 1 and 4).

7

Application No. 10/789,423

Amendment dated December 19, 2005

Reply to Office Action of September 20, 2005

However, Hayes, either alone or in combination with Kuramoto, does not suggest to one of

Docket No.: 20659/0203719-US0

Rutman

ordinary skill in the art an electromechanical device, let alone a device comprising at least two

components as described in amended claim 5.

Hayes and Kuramoto teach the use of an Au-Bi-alloy as a solder. Hayes further discloses

the application of such a solder for joining substrates in microelectronical devices. However,

neither of these references suggests applying an Au-Bi-solder when assembling substrates with

thermoelectric material to one component, which is further joined with a second component. This

second component could be a laser diode circuit, heat sink, sensor, or an optoelectronic device

forming a complex multilayered microelectromechanical device.

Claims 5-12 and 22are therefore patentable over the applied references.

In view of the above, Applicant believes the pending application is in condition for

allowance.

Dated: December 19, 2005

Respectfully submitted,

Laura C. Brutman

Registration No.: 38,395

DARBY & DARBY P.C.

P.O. Box 5257

New York, New York 10150-5257

(212) 527-7700

(212) 527-7701 (Fax)

Attorneys/Agents For Applicant

8